Reply to the 'Comment on "Intracellular stresses in patterned cell assemblies"' by D. Tambe *et al.*, *Soft Matter*, 2014, 10, DOI: 10.1039/C4SM00597J

Michel Moussus,[a] Christelle der Loughian,[b] David Fuard,[a] Marie Courçon,[c] Danielle Gulino Debrac,[c] Hélène Delanoë-Ayari*[b] and Alice Nicolas*[a]

Tambe *et al.*[1] proposed an original method to calculate intracellular stresses, that models cell monolayers as thin elastic materials. Based on this approach, Moussus *et al.*[2] proposed a straightforward calculation of the internal stresses in cellular assemblies, valid either for a single cell or a cellular monolayer. As pointed out by Tambe *et al.* in their comment, this approach relies on the assumption that cell forces generate a displacement field that is continuously transmitted to the extracellular matrix. Under this assumption, the displacement field measured at the surface of the extracellular matrix can then be differentiated to calculate the stresses inside the cellular assembly. Tambe *et al.* put this assumption into question, based on the assertion that cells only exert stresses at discrete adhesion sites, known as focal adhesions, so that elsewhere, there is *a priori* no contact, no stress and no continuity in the displacement field.

It is of no doubt that cellular stresses only transmit to the extracellular matrix at points of adhesion. However, determining the true cell contact region is very difficult, all the more on deformable substrates. Tambe *et al.*[1] circumvent this issue by calculating intracellular stresses from the cell/matrix forces they compute as the first step. In principle, this approach is more reliable since the calculation of cell/matrix forces is not endangered by the limited knowledge of cell contact regions. However, practically, results shown by traditional traction force calculations, as obtained in ref. 1 or in more resolved imaging[3,4] with different techniques, do not show any void regions in stresses as long as no assumptions are made on the regions where the forces apply:[5] cells pull on the matrix everywhere below them. This spread force field probably comes from the loss of information that originates from the regularization step, all the more that the optical resolution is low.[5] But it is this calculated force field which is employed in Monolayer Stress Microscopy (MSM) calculations.[1] So, in MSM, forces indeed apply everywhere. The displacement field is therefore continuous, meeting our working assumption. We can then argue that

[a]*LTM c/o CEA Léti, Université Joseph Fourier, CNRS UMR 5129, 17 av des Martyrs, F-38054 Grenoble cedex, France. E-mail: alice.nicolas@cea.fr*

[b]*Institut Lumière Matière, UMR5306 Université de Lyon 1-CNRS, Université de Lyon, 69622, Villeurbanne cedex, France. E-mail: helene.delanoe-ayari@univ-lyon1.fr*

[c]*Université Joseph Fourier, INSERM U1036, Commissariat à l'Energie Atomique et aux Energies Alternatives (CEA), Dpt des Sciences du Vivant (DSV), Institut de Recherches en Technologies et Sciences du Vivant (iRTSV), F-38054 Grenoble, France*

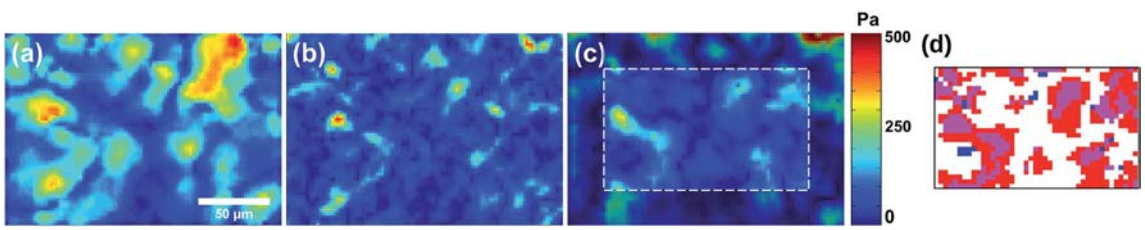


Fig. 1 Consistency of the calculated cell to matrix stresses obtained from the intracellular stresses as calculated in ref. 2, or from the Boussinesq equation using the measured displacement field on the top of the extracellular matrix. (a) Intracellular stresses in the monolayer calculated as in ref. 2. (b) Cell to matrix stresses calculated using *h*div σ from (a). (c) Cell to matrix stresses calculated using the Boussinesq equation. Regions where the boundary conditions in Boussinesq equations have an influence are shaded. *Eh* has been optimized to 50 kPa µm. (d) Superposition of the force fields from (b) (in blue) and (c) (in red). Only the stresses above 50 Pa are considered. Shaded areas in (c) are excluded. The pattern of stress from (b) colocalizes with the pattern of stress from (c), although (c) is more spread as expected from the regularization step.

both MSM and our straightforward calculation are using the same hypothesis of continuity of the displacement field.

Going beyond this assumption would probably improve both methods. At the present time however, results based on this assumption are surprisingly consistent, showing that the error it brings does not exceed for instance the error that comes from the regularization step in cell/matrix force calculation. To prove it, we calculate back the corresponding stress field $\vec{T}$ that stresses the extracellular matrix from our direct intracellular stress calculation on a monolayer, using: div $\sigma = \vec{T}/h$, where h is the thickness of the cellular assembly. Fig. 1 shows very good agreement with the traction force field calculated using the Boussinesq equation. Comparing both calculations also enables us to calibrate our method and gives us a measurement of the Young's modulus times the thickness of the monolayer, Eh, which in this case proves to be around 50 kPa μm (higher than the one initially used in ref. 2). In addition, we also believe that the sensitivity to the heterogeneity in the Young's modulus would be equivalent in both methods (compare Fig. 4k in ref. 6 and eqn (2) in ref. 2).

Finally, we want to stress that avoiding two matrix inversions (which is mandatory in MSM) is really a gain of accuracy and rapidity as important errors are linked to these numerical processes which necessitate (direct or hidden) regularization techniques.[5]

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